## NSN 5961-01-133-4566

**Fiig:** A110a0

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-133-4566 **Inclosure Material:** Glass **Overall Length:** 0.170 inches **Terminal Length:** 1.000 inches **Overall Diameter:** 0.076 inches **End Application:** Data link; aircraft, c-2a (reprocured); helicopter, h-53e; emory s. Land class as; helicopter, advance attack, ah-1w; 2m/ate microminiauture automatic test equipment; tarawa class lha; landing craft air cushion (lcac); helicopter, search and rescue, hh-60h; helicopter, uscg search and rescue, hh-60j **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 100.0 reverse voltage, peak **Power Rating Per Characteristic:** 250.0 milliwatts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Special Features:** Hardness critical process **Nuclear Hardness Critical Feature:** Hardened **Terminal Type And Quantity:** 2 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:** No